

## 1.5A Dual High-Speed Power MOSFET Drivers

#### **Features**

- High Peak Output Current: 1.5A
- Wide Supply Voltage Operating Range: 4.5V to 25V
- High Capacitive Load Drive Capability
   1000pF in 11ns (typical)
- Short Delay Times: 35ns (typical)
- Matched Rise/Fall Times
- Low Output Impedance
- Low Supply Current
- Over-temperature Protection
- Under-voltage Lockout
- Non-overlapped Drive Tech
- ESD Protected: 2.0kV
- Input withstands negative inputs up to 5V
- Available in Green SOP8, DIP8 and DFN8
   Packages

## **Applications**

- Wireless Power Transmitter
- Switch Mode Power Supplies
- Power MOSFET Drivers
- Pulse Transformer Drivers
- Line Drivers
- CCD Driver
- Class D Switching Amplifiers

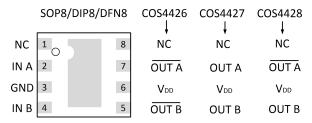
#### Rev12

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#### **General Description**

The COS4426/7/8 are matched dual power MOSFET drivers. Unique circuit design enables high speed operation capable of delivering peak currents of 1.5A into 1000pF capacitive loads. Improved speed and drive capability are enhanced by matched rise and fall delay times. These matched delays maintain the integrity of input-to-output pulse-widths to reduce timing errors and clock skew problems. Dynamic switching losses are minimized with non-overlapped drive techniques. These devices are highly latch-up resistant within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking (of either polarity) occurs on the ground pin. All terminals are fully protected against Electrostatic Discharge (ESD) up to 2.0 kV.

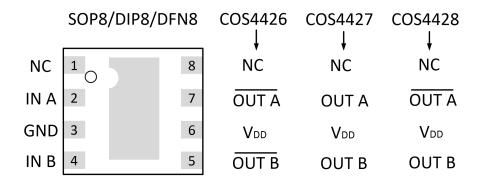
### **Pin Configuration**



COS4426: Outputs out of phase with inputs
COS4427: Outputs in phase with inputs
COS4428: OutputA: out of phase with input A
OutputB in phase with input B



# 1. Pin Configuration and Functions



COS4426: Outputs out of phase with inputs

COS4427: Outputs in phase with inputs

COS4428: Output A: out of phase with input A;

Output B: in phase with input B

Figure 1. Pin Diagram

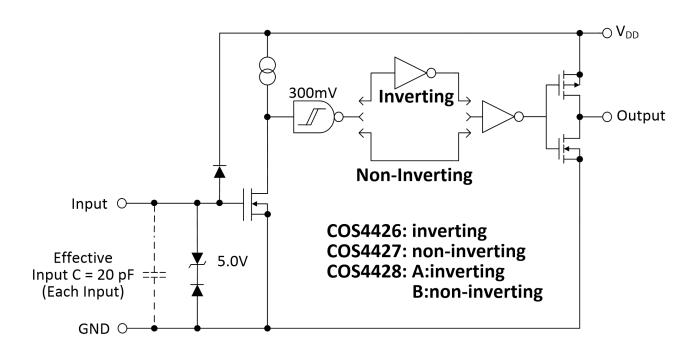


Figure 2. Functional Block Diagram



#### Pin Description

Pin	Name	Description
1	NC	No connection
2	IN A	Input A
3	GND	Ground
4	In B	Input B
5	OUT B	Output of Channel B
6	VDD	Power Supply
7	OUT A	Output of Channel A
8	NC	No connection
-	PAD	Exposed Metal Pad of DFN Package

#### **Function Table**

		COS4426		COS4427		COS4428	
INA	INB	OUTA	OUT B	OUTA	OUTB	OUTA	OUTB
L	L	Н	Н	L	L	Н	L
L	Н	Н	L	L	Н	Н	Н
Н	L	L	Н	Н	L	L	L
Н	Н	L	L	Н	Н	L	Н

#### 1.1 Inputs A and B

MOSFET driver inputs A and B are high-impedance, TTL/CMOS compatible inputs. These inputs also have 300 mV of hysteresis between the high and low thresholds that prevents output glitching even when the rise and fall time of the input signal is very slow.

#### 1.2 Ground (GND)

Ground is the device return pin. The Ground pin(s) should have a low-impedance connection to the bias supply source return. High peak current flows out the Ground pin(s) when the capacitive load is being discharged.

#### 1.3 Output A and B

MOSFET driver outputs A and B are low-impedance, CMOS push-pull style outputs. The pull-down and pullup devices are of equal strength, making the rise and fall times equivalent.



#### 1.4 Supply Input (V<sub>DD</sub>)

The VDD input is the bias supply for the MOSFET driver and is rated for 4.5V to 25V with respect to the Ground pin. The VDD input should be bypassed with local ceramic capacitors. The value of these capacitors should be chosen based on the capacitive load that is being driven. A value of 1.0  $\mu$ F is suggested.

#### 1.5 Exposed Metal Pad

The exposed metal pad of the DFN-8 package is not internally connected to any potential. Therefore, this pad can be connected to a ground plane or other copper plane on a Printed Circuit Board (PCB), to aid in heat removal from the package.

### 2. Product Specification

#### 2.1 Absolute Maximum Ratings (1)

Parameter	Min	Max	Unit
DC supply voltage Vs		26	V
Operating junction temperature	-40	125	°C
Storage temperature	-55	150	°C
Maximum input voltage	GND-5	V <sub>DD</sub> +0.3	V
Combined peak output current		4	Α

<sup>(1)</sup> Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

#### 2.2 Thermal Data

Parameter	Rating	Unit	
Package Thermal Resistance	155 (SOP8) 90 (DIP8) 57 (FDN8,3x3)	°C/W	

#### 2.3 Recommended Operating Conditions

Parameter	Rating	Unit
DC Supply Voltage	4.5V ~ 25V	V
Operating ambient temperature	-40 to +85	°C



### 2.4 Electrical Characteristics

(Typical values are tested at T<sub>A</sub>=25 °C, V<sub>DD</sub>=18V)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
INPUT				1		'
Input Signal High Threshold	V <sub>IH</sub>	1.8			V	
Input Signal Low Threshold	V <sub>IL</sub>				0.7	V
Input Signal Hysteresis	V <sub>HYS</sub>			0.3		V
Input Current	I <sub>IN</sub>	$0V \leq V_{IN} \leq V_{DD}$			±1	μA
ОИТРИТ						
Pull-Up Resistance	RoH	Source Current = 10mA		2.0		Ω
Pull-Down Resistance	R <sub>OL</sub>	Sink Current = -10mA		2.0		Ω
		Source Current, f=1kHz, C <sub>1</sub> =1000pF		1.5		
Peak Output Current	I <sub>PK</sub>	C <sub>L</sub> =1000pF         Sink Current, f=1kHz,         C <sub>L</sub> =1000pF		-1.5		A
Continuous Output Current	I <sub>DC</sub>	Source / Sink Current		±200		mA
POWER SUPPLY						
Davies Cumply Cumpant		V <sub>INA</sub> =V <sub>INB</sub> =3V		0.8		A
Power Supply Current	Icc	V <sub>INA</sub> =V <sub>INB</sub> =0V		0.4		mA
Operating Voltage Range	V <sub>DD</sub>		4.5		25	V
Under-Voltage Lockout ON Threshold				3.6	4	V
Under-Voltage Lockout Hysteresis				0.5		V
SWITCHING CHARACTERIS	STICS		1	•	l	
Rise Time	t <sub>R</sub>	C <sub>L</sub> =1000pF, See Figure 3.1		11		ns
Fall Time	t <sub>F</sub>	CL =1000pF, See Figure 3.1		11		ns
Turn On Delevi Time -	1	Non-inverting Input		34		ns
Turn-On Delay Time	t <sub>D1</sub>	Inverting Input		44		ns
Turn Off Dolov Time		Non-inverting Input		34		ns
Turn-Off Delay Time	t <sub>D2</sub>	Inverting Input		44		ns



OVER-TEMPERATURE PROTECTION					
Thermal Shutdown Threshold	150	°C			
Thermal Shutdown Threshold Hysteresis	25	°C			

## 3.0 Application Information

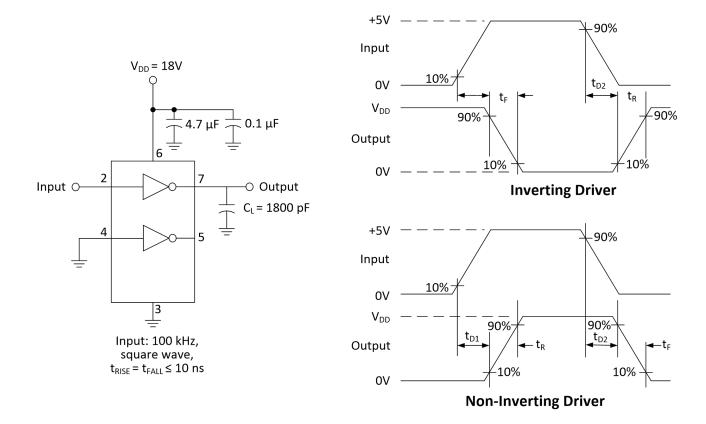


Figure 3.1 Switching Time Test Circuit

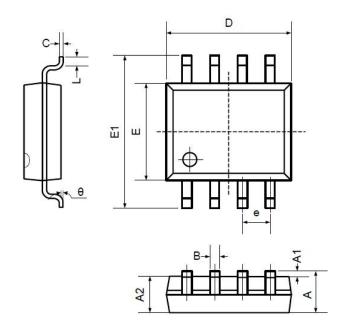
## 4.0 Package and Ordering Information

Model	Order Number	Package	Package Option	Marking Information
COS4426	COS4426SR	SOP-8	Tape and Reel, 4000	COS4426SR
COS4426	COS4426DR	DIP-8	Tube 50	COS4426DR
COS4407	COS4427SR	SOP-8	Tape and Reel, 4000	COS4427SR
COS4427	COS4427DR	DIP-8	Tube 50	COS4427DR
COC4400	COS4428SR	SOP-8	Tape and Reel, 4000	COS4428SR
COS4428	COS4428DR	DIP-8	Tube 50	COS4428DR



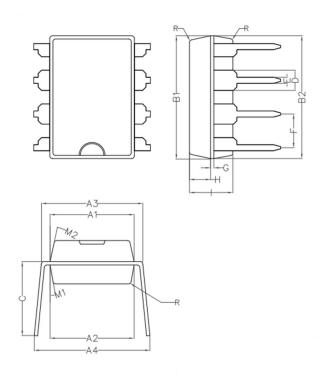
# **5.0 Package Information**

## 5.1 SOP8 (Package Outline Dimensions)



Symbol	Dimer In Milli	sions meters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
В	0.330	0.510	0.013	0.020	
С	0.190	0.250	0.007	0.010	
D	4.780	5.000	0.188	0.197	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.300	0.228	0.248	
е	1.270TYP		0.050	TYP	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

## **5.2 DIP8 (Package Outline Dimensions)**



Symbol	Min	Non	Max
A1	6.28	6.33	6.38
A2	6.33	6.38	6.43
A3	7.52	7.62	7.72
A4	7.80	8.40	9.00
B1	9.15	9.20	9.25
B2	9.20	9.25	9.30
С		5.57	
D		1.52	
E	0.43	0.45	0.47
F		2.54	
G		0.25	
Н	1.54	1.59	1.64
1	3.22	3.27	3.32
R		0.20	
M1	9°	10°	11°
M2	11°	12°	13°